

SOD-123 封装二极管/SOD-123 Plastic-Encapsulate Diodes

B5817WX/B5818WX/B5819WX (SCHOTTKY DIODES)

特点/Features:

正向导通电压低;

用途/Applications:

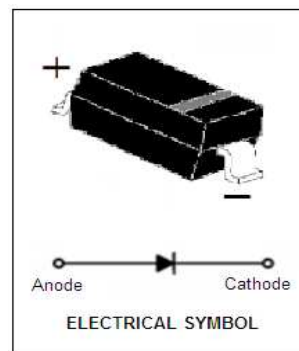
低压、高频等保护电路。

印章/ Marking:

B5817WX: SJ

B5818WX: SK

B5819WX: SL



极限参数/Absolute maximum ratings (Ta=25℃)

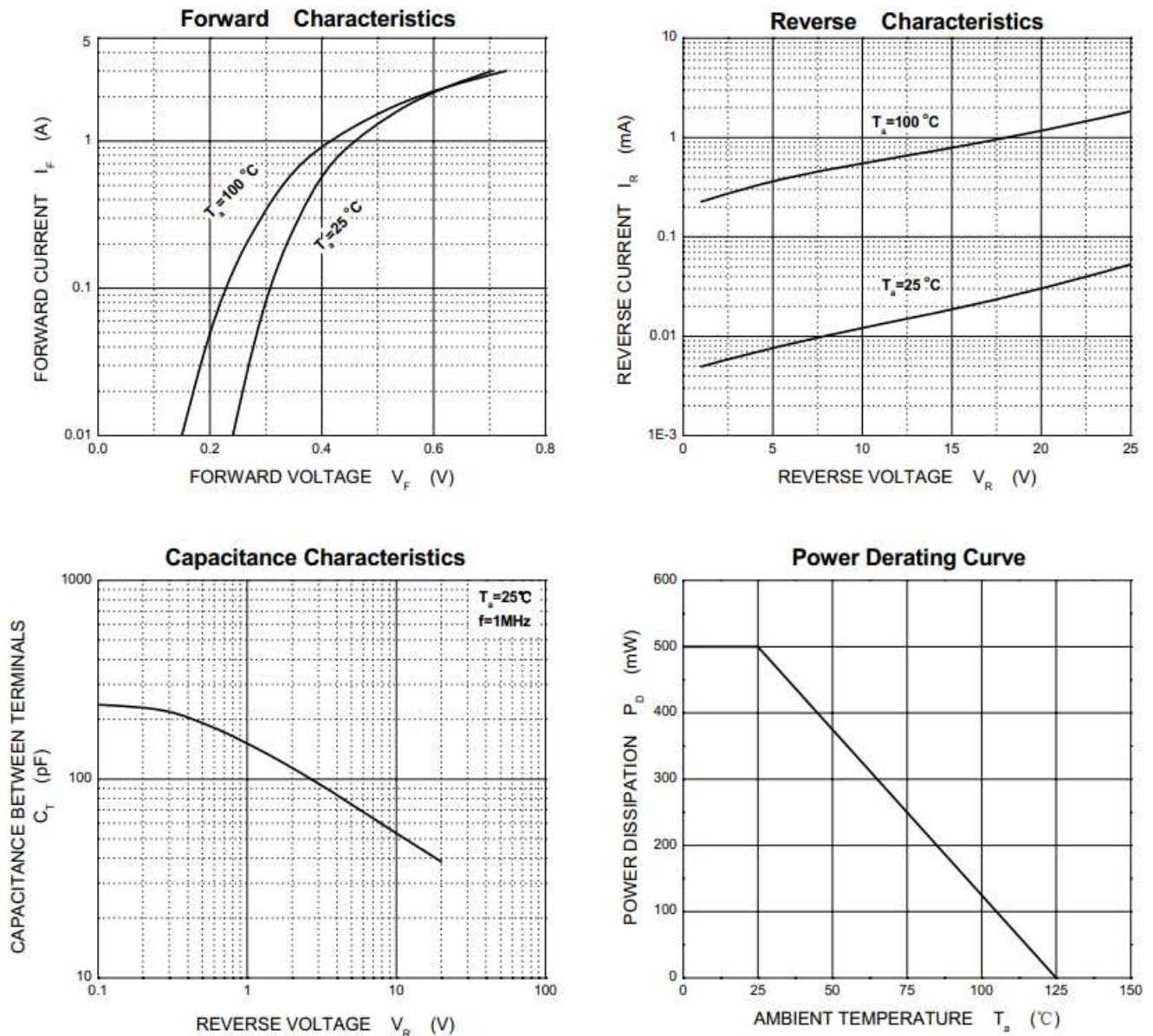
Parameter	Symbol	B5817WX	B5818WX	B5819WX	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	20	30	40	
Peak Repetitive Peak Reverse Voltage	V_{RRM}				
Working Peak	V_{RWM}	20	30	40	V
DC Blocking Voltage	V_R				
RMS Reverse Voltage	$V_{R(RMS)}$	14	21	28	V
Average rectified output current	I_O	1			A
Peak Forward Surge Current (@t≤8.3mS)	I_{FSM}	9			A
Repetitive Peak Forward Current	I_{FRM}	1.5			A
Power Dissipation	P_d	500			mW
Thermal Resistance Junction To Ambient	$R_{\theta JA}$	200			℃/mW
Storage Temperature	Tstg	-55~150			℃

电性能参数/Electrical characteristics (Ta=25℃)

参数/Parameter	符号	测试条件	最小值	典型值	最大值	单位
Reverse Breakdown Voltage B5817WX B5818WX B5819WX	$V_{(BR)}$	$I_R=1mA$	20 30 40			V
Forward Voltage	V_F	$I_F=1A$ B5817WX B5818WX B5819WX			0.45 0.55 0.6	V
		$I_F=3A$ B5817WX B5818WX B5819WX			0.75 0.875 0.9	V
Reverse voltage leakage current B5817WX B5818WX B5819WX	I_R	$V_R=20V$ $V_R=30V$ $V_R=40V$			1	mA
Diode Capacitance	C_D	$V_R=4V, f=1.0MHz$			120	pF

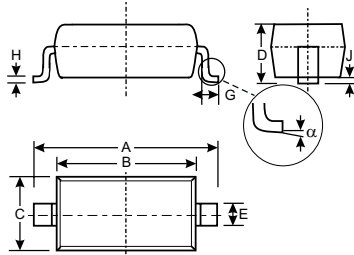
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典型特性曲线图/Typical Characteristics



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PACKAGE MECHANICAL DATA

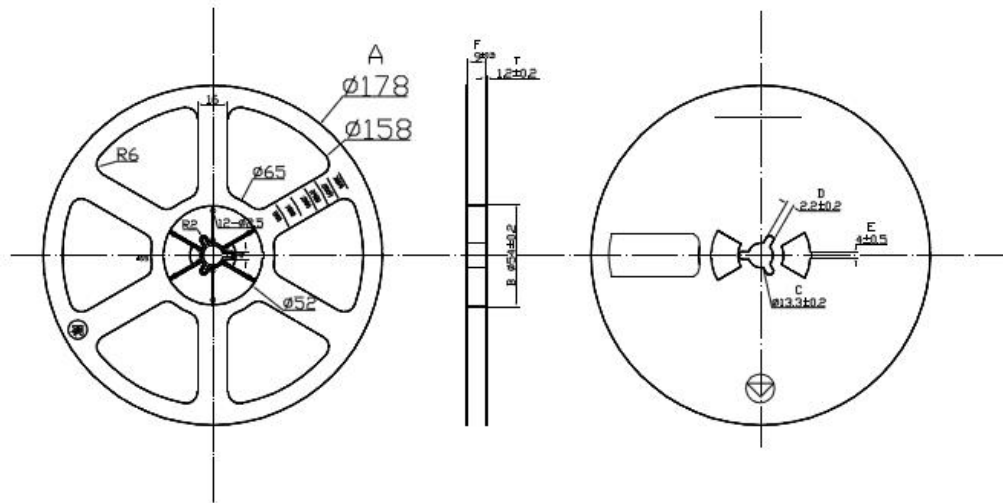


SOD-123		
Dim	Min	Max
A	3.55	3.85
B	2.55	2.85
C	1.40	1.70
D	—	1.35
E	0.55 Typical	
G	0.25	—
H	0.11 Typical	
J	—	0.10
α	0°	8°
All Dimensions in mm		

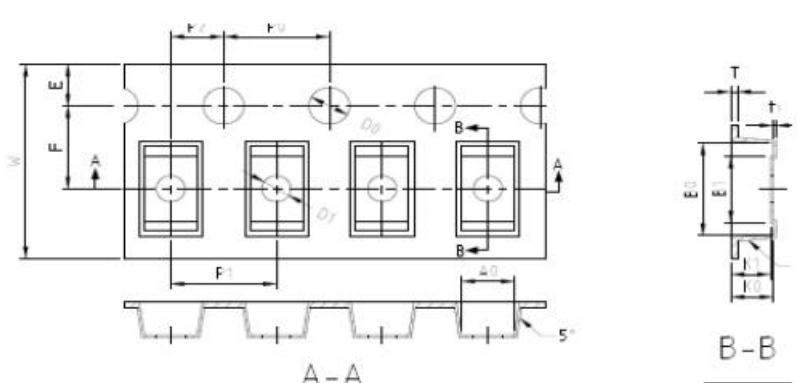
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编带料盘规格

Tape and Reel Specification



Symbol	Spec	Symbol	Spec	名称: SOD-123
W	8.00±0.10	A ₀	1.80±0.10	
E	1.75±0.10	B ₀	3.90±0.10	
F	3.50±0.10	K ₀	1.35±0.10	
D _O	1.55±0.05	B ₁	2.80±0.10	
D ₁	1.10±0.10	K ₁	1.25±0.10	
P ₀	4.00±0.10	10P ₀	40.00±0.20	
P ₁	4.00±0.10			
P ₂	2.00±0.1			
t	0.19-0.22			
t ₁	0.05以上			



A-A

B-B